

(SMALL-SIGNAL TRANSISTOR)

**2SC3440**

FOR HIGH CURRENT DRIVE APPLICATION  
SILICON NPN EPITAXIAL TYPE

**DESCRIPTION**

2SC3440 is a super mini silicon NPN epitaxial type transistor designed with high collector current, small  $V_{CE(sat)}$ .  
Complementary with 2SA1365.

**FEATURE**

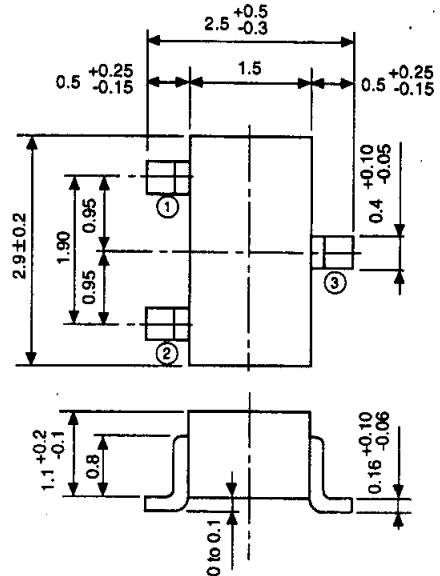
- Low collector to emitter saturation voltage  
 $V_{CE(sat)}=0.2V$  typ
- Excellent linearity of DC forward current gain
- Super mini package for easy mounting
- High collector current  $I_{CM}=1A$
- High gain band width product  $f_T=180MHz$  typ

**APPLICATION**

Small type motor drive, relay drive, power supply.

**OUTLINE DRAWING**

Unit:mm



TERMINAL CONNECTOR

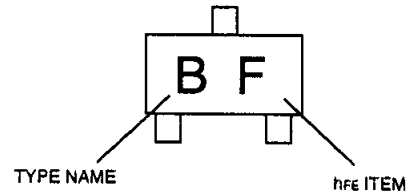
- ① : BASE EIAJ : SC-59
- ② : EMITTER JEDEC : TO-236 resemblance
- ③ : COLLECTOR

Note) The dimension without tolerance represent central value.

**MAXIMUM RATINGS (Ta=25°C)**

Symbol	Parameter	Ratings	Unit
$V_{CBO}$	Collector to Base voltage	25	V
$V_{EBO}$	Emitter to Base voltage	4	V
$V_{CEO}$	Collector to Emitter voltage	20	V
$I_{CM}$	Peak collector current	1	A
$I_C$	Collector current	700	mA
$P_C$	Collector dissipation(Ta=25°C)	150	mW
$T_j$	Junction temperature	+125	°C
$T_{stg}$	Storage temperature	-55 to +125	°C

**MARKING**



**ELECTRICAL CHARACTERISTICS (Ta=25°C)**

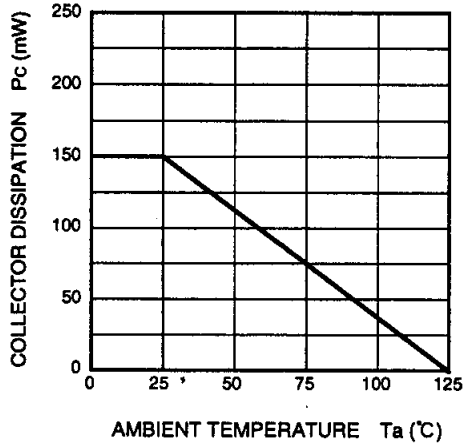
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
$V_{(BR)CBO}$	C to B break down voltage	$I_C=10 \mu A, I_E=0$	25			V
$V_{(BR)EBO}$	E to B break down voltage	$I_E=10 \mu A, I_C=0$	4			V
$V_{(BR)CEO}$	C to E break down voltage	$I_C=100 \mu A, R_{BE}=\infty$	20			V
$I_{CBO}$	Collector cut off current	$V_{CB}=25V, I_E=0$			1	$\mu A$
$I_{EBO}$	Emitter cut off current	$V_{EB}=2V, I_C=0$			1	$\mu A$
$h_{FE} *$	DC forward current gain	$V_{CE}=4V, I_C=100mA$	150		300	—
$V_{CE(sat)}$	C to E saturation voltage	$I_C=500mA, I_B=25mA$		0.2	0.5	V
$f_T$	Gain band width product	$V_{CE}=6V, I_E=-10mA$		180		MHz

\* : It shows  $h_{FE}$  classification in right table.

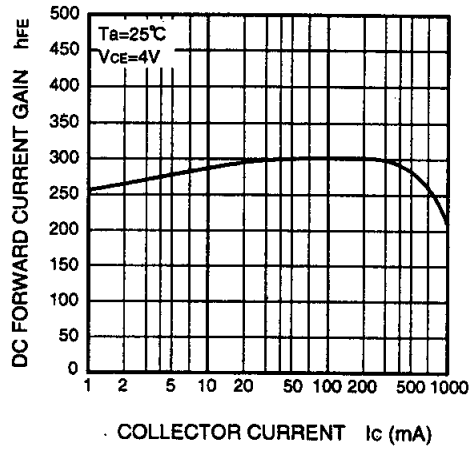
Marking	BE	BF	BG
$h_{FE}$	150 to 300	250 to 500	400 to 800

TYPICAL CHARACTERISTICS

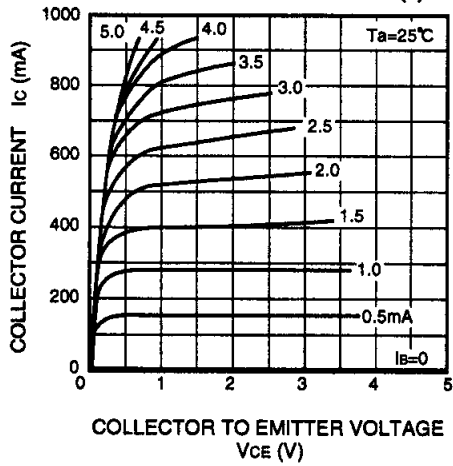
COLLECTOR DISSIPATION VS.  
AMBIENT TEMPERATURE



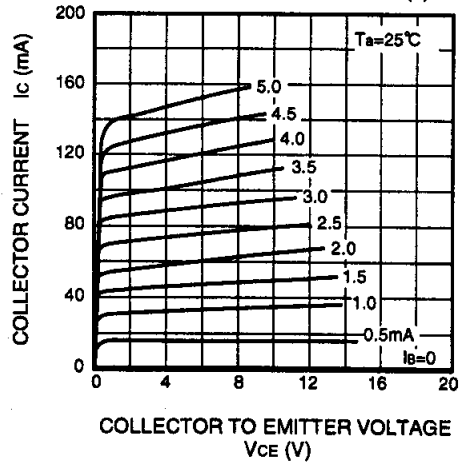
DC FORWARD CURRENT GAIN VS.  
COLLECTOR CURRENT



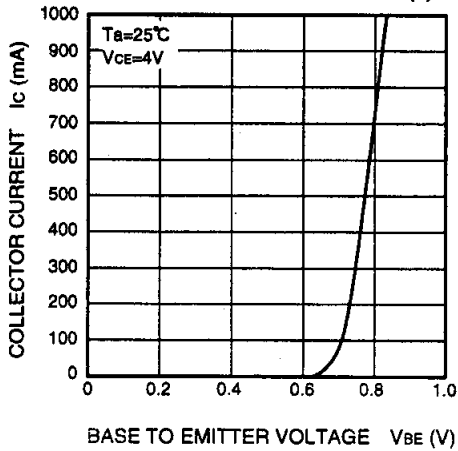
COMMON EMITTER OUTPUT (1)



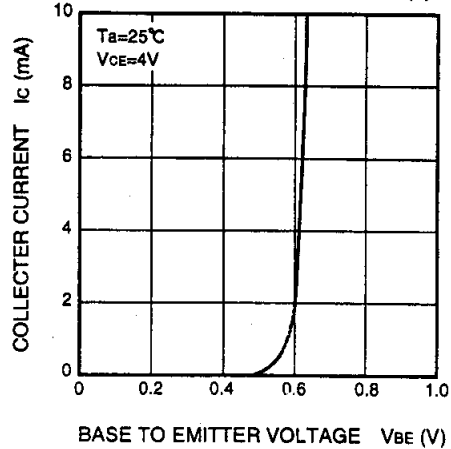
COMMON EMITTER OUTPUT (2)



COMMON EMITTER TRANSFER (1)



COMMON EMITTER TRANSFER (2)



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